

isc Silicon NPN Power Transistor

2SC4881

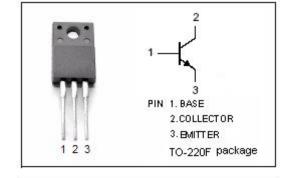
DESCRIPTION

- · Collector-Emitter Breakdown Voltage-
 - : V_{(BR)CEO}= 50V(Min)
- · High Switching Speed
- · Low Collector Saturation Voltage-
 - : $V_{CE(sat)}$ = 0.4V(Max)@ (I_C= 2.5A, I_B= 125mA)
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



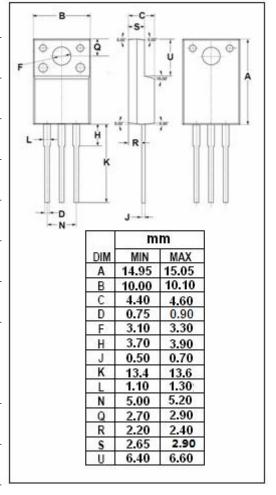
APPLICATIONS

• Designed for high current switching applications.



ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT	
V _{CBO}	Collector-Base Voltage	60	V	
V _{CEO}	Collector-Emitter Voltage	50	V	
V _{EBO}	Emitter-Base Voltage	5	V	
Ic	Collector Current-Continuous	5	Α	
Ісм	Collector Current-Pulse	8	Α	
I _B	Base Current-Continuous	1	Α	
Рт	Total Power Dissipation @Tc=25℃	20	w	
	Total Power Dissipation @T _a =25°C	2.0		
TJ	Junction Temperature	150	$^{\circ}$	
T _{stg}	Storage Temperature -55~150		$^{\circ}$	





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ELECTRICAL CHARACTERISTICS

Tj=25℃ unless otherwise specified

1)-20 C unless otherwise specified									
SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT			
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	I _C = 10mA; I _B = 0	50			V			
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 2.5A; I _B = 125mA			0.4	V			
V _{BE(sat)}	Base-Emitter Saturation Voltage	I _C = 2.5A; I _B = 125mA			1.3	V			
Ісво	Collector Cutoff Current	V _{CB} = 50V ; I _E = 0			1	μА			
ІЕВО	Emitter Cutoff Current	V _{EB} = 6V; I _C = 0			1	μА			
h _{FE-1}	DC Current Gain	I _C = 1A ; V _{CE} = 1V	100		320				
h _{FE-2}	DC Current Gain	I _C = 2.5A ; V _{CE} = 1V	60						
Сов	Output Capacitance	I _E = 0 ; V _{CB} = 10V; f= 1.0MHz		45		pF			
f⊤	Current-Gain—Bandwidth Product	I _C = 1A; V _{CE} = 4V		100		MHz			
Switching times									
t _{on}	Turn-on Time			0.1		μS			
t _{stg}	Storage Time	R_L = 12 Ω , I_{B1} = - I_{B2} = 125mA, V_{CC} = 30V		0.8		μS			
t _f	Fall Time			0.1		μS			

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